Superconductivity at 22 K in Co-Doped BaFe$_2$As$_2$ Crystals

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Here we report bulk superconductivity in BaFe$_{1.8}$Co$_{0.2}$As$_2$ single crystals below $T_c = 22$ K, as demonstrated by resistivity, magnetic susceptibility, and specific heat data. Hall data indicate that the dominant carriers are electrons, as expected from simple chemical reasoning. This is the first example of superconductivity induced by electron doping in this family of materials. In contrast with cuprates, the BaFe$_2$As$_2$ system appears to tolerate considerable disorder in the FeAs planes. First principles calculations for BaFe$_{1.8}$Co$_{0.2}$As$_2$ indicate the interband scattering due to Co is weak.

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The recent discovery of high superconducting transition temperatures in FeAs based compounds has generated great interest in the scientific community. In the oxypnicotide system $R$FeAsO ($R = $ Pr, Sm, Nd, Gd), electron- or hole-doping has produced critical temperatures ($T_c$) as high as 56 K [1–14]. In the oxygen-free compounds of AFe$_2$As$_2$ ($A = $ Ca, Sr, Ba), hole-doping has reached $T_c$ values of 38 K [15,16]. This is the first report of superconductivity in BaFe$_2$As$_2$, induced by electron-doping with cobalt on the Fe site. Since superconductivity in FeAs based compounds coincides with the disappearance of a spin-density-wave type magnetic transition, spin fluctuations of Fe are suggested to be important in developing the superconducting ground state [17]. It is found that by introducing holes in the (FeAs)$^-$ layers, by K doping in BaFe$_2$As$_2$ for example, the structural and magnetic phase transition at approximately 140 K ($T_m$) is suppressed and superconductivity is found [15,18]. This scenario is very similar to the arsenide oxide superconductors [19,20]. Chemically, cobalt has advantages as a dopant since carriers are added directly into the FeAs planes, and cobalt is much easier to handle than alkali metals. We have recently reported bulk superconductivity for $\sim$4--12% Co doping levels in LaFeAsO, giving onset transition temperature up to $T_c^{\text{onset}} = 14.3$ K in LaFe$_{0.92}$Co$_{0.08}$AsO [14]. Here we report superconductivity in 8.0(5)% cobalt doped BaFe$_2$As$_2$ single crystals, giving $T_c^{\text{onset}} = 22$ K. The relatively high $T_c$ is exciting as it demonstrates that in-plane disorder is highly tolerated.

Large single crystals of BaFe$_2$As$_2$ and Co-doped BaFe$_2$As$_2$ were grown out of FeAs flux, allowing for intrinsic property investigation. The typical crystal sizes from both batches were $\sim 8 \times 5 \times 0.2$ mm$^3$. The crystals were brittle, well-formed plates with the [001] direction perpendicular to the plane of the crystals. Energy-dispersive X-ray spectroscopy (EDS) analyses [2] on several crystals indicated that 8.0(5)% of the Fe is replaced by Co in BaFe$_2$As$_2$. Thus, the composition will be presented as BaFe$_{1.8}$Co$_{0.2}$As$_2$.

The phase purity of the crystals was determined using a Scintag XDS 2000 $2\theta$-$2\theta$ diffractometer (Cu K$_\alpha$ radiation). The parent and Co-doped BaFe$_2$As$_2$ crystallize with the ThCr$_2$Si$_2$ [21,22] structure, in tetragonal space group symmetry $I4/mmm$ (No. 139; $Z = 2$) at room temperature. The crystal structure is made up of $\text{Ba}_0.3^2\text{Co}(\text{FeAs})^5_-$ for the parent, with partial and random substitution of Co on Fe sites for BaFe$_{1.8}$Co$_{0.2}$As$_2$. All observed reflections were indexed, limiting impurity concentrations to about 1% or less. Lattice constants were determined from LeBail refinements using the program FullProf [23]. The lattice parameters of BaFe$_2$As$_2$ are $a = 3.9635(5)$ Å and $c = 13.022(2)$ Å, consistent with a report on a polycrystalline sample [21]. The refined lattice constants of BaFe$_{1.8}$Co$_{0.2}$As$_2$ are $a = 3.9639(4)$ Å and $c = 12.980(1)$ Å. Cobalt doping results in a small decrease (0.26%) in the length of the $c$ axis, while the value of the $a$ axis is unchanged within experimental uncertainty. We have recently reported similar behavior in Co-doped LaFeAsO [14].

DC magnetization was measured as a function of temperature and field using a Quantum Design MPMS. Figure 1(a) shows the measured magnetic susceptibility ($\chi$) in zero-field-cooled (zfc) form for BaFe$_2$As$_2$ in 1 kOe applied field along $c$- and $ab$-crystallographic directions. The susceptibility is anisotropic and decreases slightly with decreasing temperature down to $\approx 140$ K, at which point it drops more abruptly, due to a magnetic and structural phase transition [21]. As can be seen in Fig. 1(b), $\chi$ for BaFe$_{1.8}$Co$_{0.2}$As$_2$ varies smoothly between $\approx 22$ and 300 K without any abrupt drop, indicating the disappearance of magnetic ordering in the doped system.

Shown in Fig. 1(c) is the $4\pi$X$_{\text{eff}}$ versus $T$ measured along the $ab$ plane at an applied field of 20 Oe for BaFe$_{1.8}$Co$_{0.2}$As$_2$, where $X_{\text{eff}}$ is the effective magnetic susceptibility after demagnetization effect correction. Since the magnetization varied linearly with fields below 100 Oe at 1.8 K, we assume that the system is fully shielded; therefore, the effective magnetic susceptibility for $zfc$...
behavior above 200 Oe, suggesting that the lower critical
Magnetization versus magnetic field deviates from linear
of the perfect diamagnetism. (d) Field dependence of magneti-
BaFe$_1$Co$_0$As$_2$: $H_p$ is another peak that occurs at
$H_c$, when the magnetic field increases along both the $c$- and
-crystallographic directions. At present it is unclear
whether this is due to the fish tail effect as observed in
-high-$T_c$ cuprates [26], and more measurements are
underway.

Temperature dependent electrical resistivity was per-
formed on a Quantum Design PPMS, measured in the $ab$
plane. For BaFe$_2$As$_2$ [inset of Fig. 2(a)], the room tem-
perature $\rho_{300K} = 5.9 \, \text{m}\Omega \, \text{cm}$; this value is comparable to
that reported [18]. The resistivity drops below $\sim 150 \, \text{K}$
with decreasing temperature, reaching $\rho_{2K} =
5.0 \, \text{m}\Omega \, \text{cm}$. While both BaFe$_2$As$_2$ and BaFe$_{1.8}$Co$_0$As$_2$ show
metallic behavior, the resistivity for BaFe$_{1.8}$Co$_0$As$_2$ is much smaller than for the parent
compound. For BaFe$_{1.8}$Co$_0$As$_2$ as the temperature is lowered
down to 22 K, an abrupt drop in $\rho_{ab}$ is observed [Fig. 2(a)].

The onset transition temperature for 90% fixed percentage
of the normal-state value is $T_c \text{ onset} = 22 \, \text{K}$ at 0 T. The transition
width in 0 T is $\Delta T_c = T_c(90\%) - T_c(10\%) = 0.6 \, \text{K}$. The $\Delta T_c$
value is much smaller that that reported for
LaFe$_{0.92}$Co$_{0.08}$AsO $\Delta T_c = 2.3 \, \text{K}$ [14], and for
LaFeAsO$_{0.89}$Fe$_{0.11}$ $\Delta T_c = 4.5 \, \text{K}$ [2]. The resistive transition
shifts to lower temperatures by applying an 8 T mag-
netic field, and transition width becomes wider (1.3 K), a
characteristic of type-II superconductivity.

For the Hall-effect measurements, a rectangular-shaped
single-crystalline platelet of BaFe$_{1.8}$Co$_0$As$_2$ was selected
with a thickness of 0.05 mm. Four electrical contacts were
made using silver epoxy. The Hall voltage was calculated
from the antisymmetric part of the transverse voltage
(perpendicular to the applied current) under magnetic-field
data is $\chi_{\text{eff}} = -1/(4\pi)$. The demagnetization factor $N$
was then obtained via $N = (\chi^{-1} - \chi_{\text{eff}}^{-1})$; $N = 11.3$ for
$H \parallel c$ and 5.7 for $H \parallel ab$. The $\chi_{\text{eff}}$ at different temperatures
was calculated using $N$ and measured $\chi$ via $\chi_{\text{eff}} =
\chi/(1 - N \chi)$. Note that the $\chi_{\text{eff}}$ data decrease rapidly
for temperatures below $\sim 22 \, \text{K}$ and quickly saturates
to 1. This indicates that the system is indeed fully shielded
and the substitution of cobalt on Fe-site is more homoge-
 nous than the use of other dopants such as fluorine in
LaFeAsO$_{1-x}$F$_x$ [2] or potassium in Ba$_{1-x}$K$_x$Fe$_2$As$_2$ [15]
for which the transitions are broadened. However, the $fc$
$4\pi \chi_{\text{eff}}$ saturates at a much smaller value (< 0.01), proba-
ably reflecting strong pinning due to the Co dopant. This
is further confirmed by $M$ versus $H$ at 1.8 K [Fig. 1(d)].
Magnetization versus magnetic field deviates from linear
behavior above 200 Oe. suggesting that the lower critical
field $H_{c1}$ is approximately 200 Oe. However, $M(H)$ does
not reach zero in applied fields up to 7 T, indicating that the
upper critical field $H_{c2}$ is much higher than 7 T.
Nevertheless, one may estimate the critical current by
measuring the magnetization hysteresis loop as shown in
Fig. 1(d). Using the Bean critical state model [24], we
obtain a $J_c$ value along the $ab$ plane of $\approx 1.8 \times
10^4 \, \text{A cm}^{-2}$. This large $J_c$ results from strong pinning
effects. Although the magnetization hysteresis loop is also
measured along the $c$ axis, it is nontrivial to calculate
$J_c$ as $H$ is not along the symmetry axis [25]. In view of the
magnetization loops, we note that in addition to the peak
penetration field, $H_p$, there is another peak that occurs at
$H_c$, when the magnetic field increases along both the $c$- and
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FIG. 1 (color online). Temperature dependence of molar susceptibility in zero-field-cooled ($zfc$) forms along the two crys-
tallographic directions for (a) BaFe$_2$As$_2$ in 1 kOe and
(b) BaFe$_{1.8}$Co$_0$As$_2$ in 1 T. (c) The temperature dependence of susceptibility in $zfc$ and field-cooled ($fc$) forms below 30 K, for
BaFe$_{1.8}$Co$_0$As$_2$ in 20 Oe along the $ab$ plane, assuming $\chi$ value of the perfect diamagnetism. (d) Field dependence of magneti-
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FIG. 2 (color online). (a) Temperature dependence of resistivity for BaFe$_{1.8}$Co$_0$As$_2$, measured below 30 K, at 0 and 8 T
applied magnetic fields. Inset is the temperature dependence of BaFe$_2$As$_2$ and BaFe$_{1.8}$Co$_0$As$_2$ up to room temperature at 0 T.
(b) Hall coefficient $R_H$ versus temperature for BaFe$_{1.8}$Co$_0$As$_2$. Inset is the field dependence of Hall resistivity at 30, 100, 200,
and 300 K.
reversal at both fixed field and temperature. Shown in Fig. 2(b) is the temperature dependence of the Hall coefficient $R_H$ taken at 8 T. Note that $R_H$ is negative between 30 and 300 K, initially becoming more negative with decrease of temperature. At lower temperatures, it becomes less negative after reaching a minimum near 100 K. As demonstrated in the inset of Fig. 2(b), $\rho_H$ varies nearly linearly with $H$ at various fixed temperatures (30, 100, 200, and 300 K), indicating no significant magnetic contributions to the measured Hall voltages. The negative $R_H$ indicates that electrons are the dominant charge carriers. The Hall coefficient of BaFe$_{1.8}$Co$_{0.2}$As$_2$ is smaller in absolute value than reported values for the superconducting oxypnictides [2].

The carrier concentration $n$ may be inferred via $n = 1/(qR_H)$; $q$ is the carrier charge. This gives $\sim 6 \times 10^{21}$ cm$^{-3}$ at 300 K. Interpretation of $R_H$ is complicated by the multiband nature of the system and the presence of both electron and hole bands at the Fermi level [27,28]. In a simple two band model, $n$ derived from $R_H$ as outlined above represents an upper bound on the actual concentration of electrons. The temperature dependence of $n$ may be more closely related to changes in relaxation rates associated with different electron and hole pockets than to the changes in carrier concentration.

Specific heat data, $C_p(T)$, for BaFe$_{1.8}$Co$_{0.2}$As$_2$ were also obtained using the PPMS via the relaxation method. We clearly observe a specific heat discontinuity below $T_c$, peaking at 20 K, confirming bulk superconductivity.

We performed density functional calculations for Co-doped BaFe$_2$As$_2$ within the local density approximation (LDA), with methodology as described in Ref. [28] for the BaFe$_2$As$_2$ parent. These were done both for a virtual crystal with Fe replaced by a virtual atom Z = 26.1 to simulate 10% Co doping, and in supercells with Ba$_2$Fe$_3$CoAs$_3$ and Ba$_4$Fe$_2$CoAs$_8$ compositions. In both cases the lattice parameters were held fixed and all internal coordinates were relaxed. The projections of the $d$-electron DOS for the Fe and Co in a Ba$_4$Fe$_2$CoAs$_8$ supercell is shown in Fig. 3(a). Note the downward shift of the states that comprise the hole sections on the Co sites. Co is more strongly hybridized with As than Fe. The calculated Fermi surface of the virtual crystal without magnetism is shown in Fig. 3(b). As may be seen in comparison with Ref. [28], the effect of Co doping on the structure of the Fermi surface at the virtual crystal level is rather similar to the effect of electron-doping on the Ba site. Turning to the supercell calculations, we find that Co is expected to strongly scatter carriers near the Fermi energy $E_F$. In particular, comparing the projections of the density of states (DOS) onto the Co and Fe sites we find that in the vicinity of the $E_F$ the Co contribution is less that 50% of that of an Fe atom. This depletion in Co contribution is even stronger below $E_F$ but the Co contribution becomes essentially the same as the Fe contribution starting from 0.2 eV above $E_F$. This is associated with a large pseudogap in the $d$ electron DOS on the Co site associated with As-Co hybridization. These Fe-based materials are low carrier density metals, with heavy hole Fermi surfaces at the zone center and lighter electron sections around the zone corner [28]. Our supercell results show that Co much more strongly affects the states forming the hole sections, which have different orbital character than the electron sections. The implications are first of all that the scattering will be stronger on the hole sections, though for low $q$ strong scattering is inevitable on both sections, and more significantly that interband scattering may be relatively weak. This is in analogy with the effect of defects on MgB$_2$, which shows two band superconductivity [29]. The intraband scattering will average the order parameter on a given Fermi surface. This will apply also for nested cylinders with similar orbital character and small $q$ spacing. Thus order parameters with nodes or sign changes (such as an axial $p$-wave state, which does not have nodes) will be destroyed, and only $s$-like states on a given set of Fermi surfaces (holes or electrons) will survive. Robustness of superconductivity in the presence of strong interband scattering would seem to lead to the same conclusion, i.e., an $s$ symmetry superconducting state.

In summary we have found superconductivity in Co-doped BaFe$_2$As$_2$ single crystals with onset superconduct-
ing transition temperature of 22 K. For 8.0(5)% cobalt doping, magnetic order is destroyed and superconductivity is induced. The bulk nature of the superconductivity and the high quality of the samples are confirmed by the anomaly in specific heat data, and narrow transition widths in both resistivity and magnetic susceptibility measurements. Hall data indicate that doping with Co produces an electron doped superconductor. These experiments and, in particular, the robustness of superconductivity against Co doping, which must introduce strong intraband scattering, shed significant light on the nature of superconductivity in these Fe-based superconductors. However, while superconductivity remarkably survives Co doping both in this system and as reported by us earlier in the oxyarsenide [14], the critical temperature in the oxyarsenide is rather strongly reduced in Co-doped samples as compared to F-doped materials. In view of this, and considering that the band structure results suggest that interband scattering due to Co may be relatively weak (note that these are high $T_c$, low Fermi velocity, short coherence length materials), we do not exclude the generalized $s$ state, e.g., where there is a phase shift or sign change between the order parameters on the hole and electron surfaces. One such scenario involving spin-fluctuations was discussed by Mazin and co-workers [30].

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